## NSN 5961-01-177-0467

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Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-177-0467 **Inclosure Material:** Metal **Overall Length:** 1.063 inches **Overall Diameter:** 2.303 inches **Internal Configuration:** Junction contact **Mounting Method:** Press fit **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 1400.0 repetitive peak off-state voltage and 1400.0 repetitive peak reverse voltage **Current Rating Per Characteristic:** 450.00 amperes forward current, total rms universal and 150.00 milliamperes source cutoff current minor **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnpn **Terminal Type And Quantity:** 2 uninsulated wire lead w/terminal lug and 1 case Shelf Life: N/a **Unit Of Measure:** Demilitarization: No Fiig: